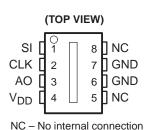
- 102 × 1 Sensor-Element Organization
- 300 Dots-Per-Inch (DPI) Sensor Pitch
- High Sensitivity
- Output Referenced to Ground
- Excellent High-Temperature Dark Signal Characteristics
- Operation to 2 MHz
- Single 5-V Supply

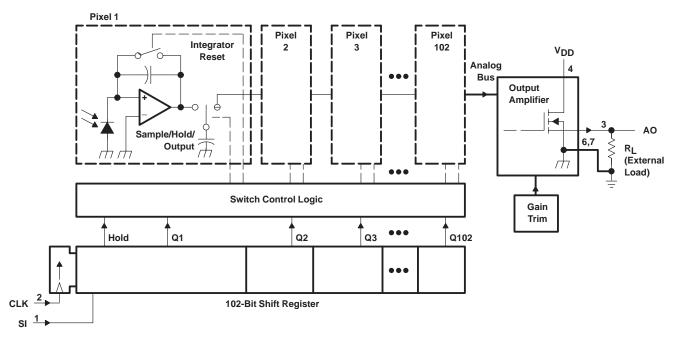
### description



The TSL1301 linear sensor array consists of a  $102 \times 1$  array of photodiodes, associated charge amplifier circuitry, and a pixel data-hold function that provides simultaneous-integration start and stop times for all pixels. The pixels measure 85  $\mu$ m by 77  $\mu$ m with 85- $\mu$ m center-to-center spacing and 8- $\mu$ m spacing between pixels. Operation is simplified by internal control logic that requires only a serial-input pulse (SI) and a clock.

The TSL1301 is intended for use in a wide variety of applications including mark and code reading, OCR and contact imaging, edge detection and positioning, and optical encoding.

### functional block diagram





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TERMINAL		DESCRIPTION					
NAME	NO.	DESCRIPTION					
AO	3	Analog output					
CLK	2	Clock. The clock controls charge transfer, pixel output, and reset.					
GND	6, 7	Ground (substrate). All voltages are referenced to the substrate.					
NC	5, 8	No internal connection					
SI	1	Serial input. SI defines the start of the data-out sequence.					
V <sub>DD</sub>	4	Supply voltage. Supply voltage for both analog and digital circuits.					

### **Terminal Functions**

### detailed description

The sensor consists of 102 photodiodes, also called pixels, arranged in a linear array. Light energy impinging on a pixel generates photocurrent, which is then integrated by the active integration circuitry associated with that pixel.

During the integration period, a sampling capacitor connects to the output of the integrator through an analog switch. The amount of charge accumulated at each pixel is directly proportional to the light intensity and the integration time.

The output and reset of the integrators is controlled by a 102-bit shift register and reset logic. An output cycle is initiated by clocking in a logic 1 on SI. This causes all 102 sampling capacitors to be disconnected from their respective integrators and starts an integrator reset period. As the SI pulse is clocked through the shift register, the charge stored on the sampling capacitors is sequentially connected to a charge-coupled output amplifier that generates a voltage on analog output AO. The integrator reset period ends 18 clock cycles after the SI pulse is clocked in. Then the next integration period begins. Note that a total 103 clock cycles are required, the 103rd cycle being necessary to terminate the output of pixel 102 and return the output to a high-impedance state, and to clear the internal shift register.

AO is driven by a source follower that requires an external pulldown resistor. When the output is not in the output phase, it is in a high-impedance state. The output is nominally 0 V for no light input and 2 V for a nominal full-scale output.



### absolute maximum ratings<sup>†</sup>

Supply voltage, V <sub>DD</sub>	
Digital input current range, I <sub>1</sub>	–20 mA to 20 mA
Operating free-air temperature range, T <sub>A</sub>	
Storage temperature range, T <sub>stg</sub>	–25°C to 85°C
Storage temperature range, T <sub>stg</sub> Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### recommended operating conditions (see Figure 1 and Figure 2)

	MIN	NOM	MAX	UNIT
Supply voltage, V <sub>DD</sub>	4.5	5	5.5	V
Input voltage, VI	0		V <sub>DD</sub>	V
High-level input voltage, VIH	$V_{DD}  imes 0.7$		V <sub>DD</sub>	V
Low-level input voltage, VIL	0		$V_{DD}  imes 0.3$	V
Wavelength of light source, $\lambda$	400		700	nm
Clock frequency, f <sub>clock</sub>	5		2000	kHz
Sensor integration time, tint	0.0515	5	100	ms
Setup time, serial input, t <sub>su(SI)</sub>	20			ns
Hold time, serial input, t <sub>h(SI)</sub> (see Note 1)	0			ns
Operating free-air temperature, TA	0		70	°C

NOTE 1: SI must go low before the rising edge of the next clock pulse.

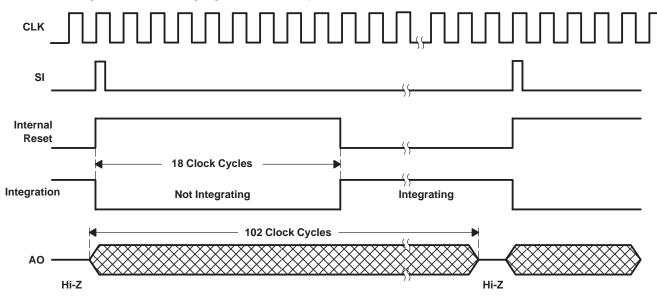


Figure 1. Timing Waveforms



# electrical characteristics at f<sub>clock</sub> = 200 kHz, V<sub>DD</sub> = 5 V, T<sub>A</sub> = 25°C, $\lambda_p$ = 565 nm, t<sub>int</sub> = 5 ms, R<sub>L</sub> = 330 $\Omega$ , E<sub>e</sub> = 800 nW/cm<sup>2</sup> (unless otherwise noted) (see Note 2)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
	Analog output voltage (white, average over 102 pixels)			1.8	2	2.2	V
	Analog output voltage (dark, average over 102 pixels)	$E_{e} = 0$		0	0.3	0.4	V
PRNU	Pixel response nonuniformity	Pixels 2–101,	See Note 3			±10%	
	Nonlinearity of analog output voltage	See Note 4			±0.5%		
	Output noise voltage	E <sub>e</sub> = 0,	See Note 5		3		mVrms
	Saturation exposure	V <sub>DD</sub> = 4.5 V		5.45	7		nJ/cm <sup>2</sup>
	Analog output saturation voltage	V <sub>DD</sub> = 4.5 V,	$R_L = 330 \ \Omega$	3	3.5		V
DSNU	Dark signal nonuniformity	All pixels, See Note 6	$E_e = 0$		0.04	0.12	V
IL	Image lag	See Note 7			1%		
I <sub>DD</sub>	Supply current	RL = 330 Ω			2.5	4	mA
ЧΗ	High-level input current	$V_I = V_{DD}$				10	μA
۱ <sub>IL</sub>	Low-level input current	$V_{I} = 0$				10	μA
Ci	Input capacitance				5		pF

NOTES: 2. Clock duty cycle is assumed to be 50%.

3. PRNU is the maximum difference between the voltage from any single pixel and the average output voltage from all pixels of the device under test when the array is uniformly illuminated.

4. Nonlinearity is defined as the maximum deviation from a best-fit straight line over the dark-to-white irradiance levels, as a percent of analog output voltage (white).

5. RMS noise is the standard deviation of a single-pixel output under constant illumination as observed over a 5-second period.

6. DNSU is the difference between the maximum and minimum of dark-current voltage.

7. Image lag is a residual signal left in a pixel from a previous exposure. It is defined as a percent of white-level signal remaining after a pixel is exposed to a white condition followed by a dark condition:

$$IL = \frac{V_{AO}^{-V}AO(dark)}{V_{AO}(white) - V_{AO}(dark)} \times 100$$



### TSL1301 102 × 1 LINEAR SENSOR ARRAY WITH HOLD SOES031A – NOVEMBER 1996 – REVISED MAY 1997

# operating characteristics over recommended ranges of supply voltage and operating free-air temperature (see Figure 2)

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
<sup>t</sup> w(H)	Clock pulse duration (high)		50		ns
tw(L)	Clock pulse duration (low)		50		ns
t <sub>s</sub>	Analog output settling time to $\pm 1\%$	$R_L = 330 \Omega$ , $C_L = 50 pF$		350	ns

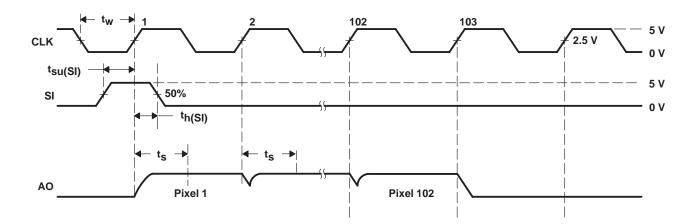


Figure 2. Operational Waveforms



## **APPLICATIONS INFORMATION**

This clear-plastic dual-in-line package consists of a circuit mounted on a lead frame and encapsulated with an electrically nonconductive clear plastic compound.

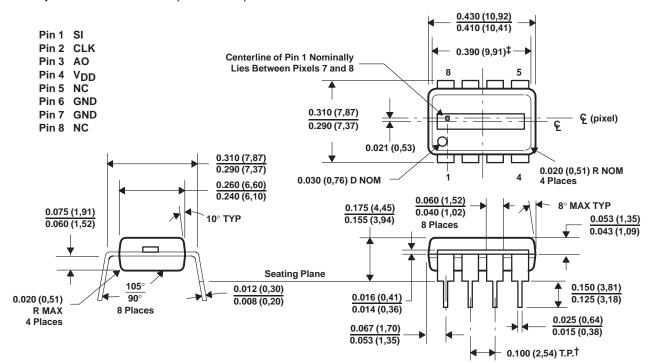


Figure 3. Packaging Configuration

<sup>†</sup>True position when unit is installed

<sup>‡</sup> Minimum flat-optical-surface length

NOTES: A. All linear dimensions are in inches and parenthetically in millimeters.

B. This drawing is subject to change without notice.



### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TSL1301	OBSOLETE	OPTO	NU	8	TBD	Call TI	Call TI

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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